

### PNP power transistors

#### **Features**

■ PNP transistors

#### **Applications**

■ Linear and switching industrial equipment

#### **Description**

The devices are manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The NPN types are BD439 and BD441.

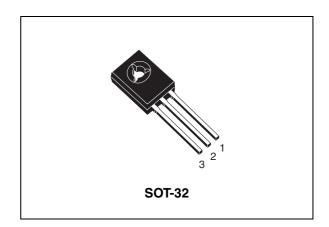


Figure 1. Internal schematic diagram

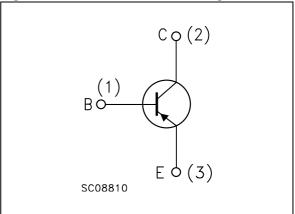


Table 1. Device summary

Order code	Marking	Package	Packaging
BD440	BD440	SOT-32	Tube
BD442	BD442	301-32	Tube

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# 1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Va	Unit	
		BD440	BD442	
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	-60	-80	V
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	-60	-80	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	-60	-80	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	-5		V
I <sub>C</sub>	Collector current	-	4	Α
I <sub>CM</sub>	Collector peak current (t <sub>p</sub> < 10 ms)	-	7	Α
I <sub>B</sub>	Base current	-	1	Α
P <sub>TOT</sub>	Total dissipation at T <sub>case</sub> = 25 °C	3	6	W
T <sub>stg</sub>	Storage temperature	-65 to 150		°C
TJ	Max. operating junction temperature	150		°C

## 2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C; \text{ unless otherwise specified})$ 

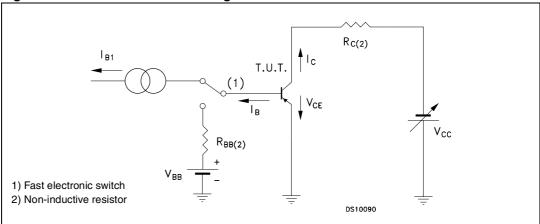
Table 3. Electrical characteristics

Symbol	Parameter	Test co	onditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current	for BD440	V <sub>CB</sub> = -60 V			-0.1	mA
,CBO	(I <sub>E</sub> = 0)	for BD442	$V_{CB} = -80 \text{ V}$			-0.1	mA
1	Collector cut-off current	for BD440	V <sub>CE</sub> = -60 V			-0.1	mA
I <sub>CES</sub>	$(V_{BE} = 0)$	for BD442	$V_{CE} = -80 \text{ V}$			-0.1	mA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = -5 V				-1	mA
	Collector-emitter	I <sub>C</sub> = -100 mA					
V <sub>CEO(sus)</sub> <sup>(1)</sup>	sustaining voltage	for BD440		-60			V
	(I <sub>B</sub> = 0)	for BD442		-80			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = -2 A	$I_B = -0.2 A$			-0.8	V
v (1)	Base-emitter voltage	$I_C = -10 \text{ mA}$	$V_{CE} = -5 V$		-0.58		٧
V <sub>BE</sub> <sup>(1)</sup>		I <sub>C</sub> = -2 A	$V_{CE} = -1 V$			-1.5	V
		I <sub>C</sub> = -10 mA	V <sub>CE</sub> = -5 V				
		for BD440		20	130		
		for BD442		15	130		
		$I_C = -500 \text{ mA}$	$V_{CE} = -1 V$				
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	for BD440		40	140		
		for BD442		40	140		
		$I_C = -2 A$	$V_{CE} = -1 V$				
		for BD440		25			
		for BD442		15			

<sup>1.</sup> Pulsed duration = 300 ms, duty cycle  $\geq$  1.5%.

#### 2.1 Test circuit

Figure 2. Resistive load switching test circuit

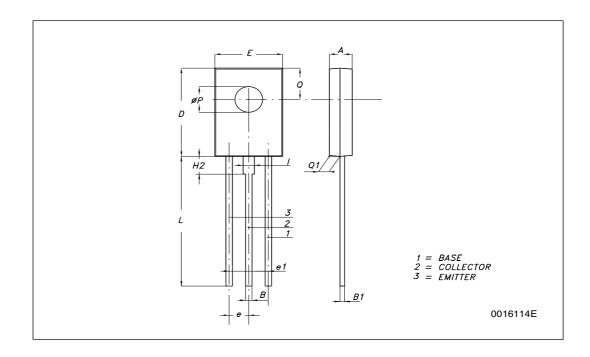


## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: <a href="https://www.st.com">www.st.com</a>

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DIM.	mm.				
DIWI.	MIN.	TYP	MAX.		
Α	2.4		2.9		
В	0.64		0.88		
B1	0.39		0.63		
D	10.5		11.05		
E	7.4		7.8		
е	2.04	2.29	2.54		
e1	4.07	4.58	5.08		
L	15.3		16		
Р	2.9		3.2		
Q		3.8			
Q1	1		1.52		
H2		2.15			
1		1.27			



BD440 BD442 Revision history

# 4 Revision history

Table 4. Document revision history

Date	Revision	Changes
08-Feb-2008	1	Initial Release

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